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Application Number	09/943,190	p,
Filing Date	August 29, 2001	iç.
First Named Inventor	Kristy A. Campbell	1
Group Art Unit	2818	
Examiner Name	Unknown 2	·
Attorney Docket Number	MI22-1668	B, .

Total Number of Pages in This Subm	Attorney Docket Number	MI22-1668							
	ENCLOSURES (check all that app	oly)							
Fee Transmittal Form	Assignment Papers (for an Application)	After Allowance Communication to Group							
Fee Attached	Drawing(s)	Appeal Communication to Board of Appeals and Interferences							
Amendment / Response	Licensing-related Papers	Appeal Communication to Group (Appeal Notice, Brief, Reply Brief)							
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SIGNATU	RE OF APPLICANT, ATTORNEY, OR	AGENT							
Firm or Individual name Mark S. Matkin Wells St. John 1	, Reg. No. 32,268 P.S.								
Signature	L AM	•							
Date	Date 10/8/02								
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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE CEIVED

Patent Application Serial No	9/9/943/990
Patent Application Serial No	TECHNUgust 29,,2001
Inventorship	Kristy A. Campbell et al. 800
Assignee	Micron Technology, Inc.
Group Art Unit	2818
Examiner	Unknown
Attorney's Docket No	MI22-1668
Title: Method of Forming Non-Volatile Resistance Varia	able Devices, Methods of
Forming a Programmable Memory Cell of Memory	ory Circuitry, and a Non-
Volatile Resistance Variable Device	1

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

References - See Attached Form PTO-1449

In compliance with 37 C.F.R. §§ 1.56, 1.97 and 1.98, your attention is directed to the United States patents and other references listed on the attached Form PTO-1449. Copies of the cited art are attached hereto. No admission is made regarding whether all the submitted references are prior art.

This Supplemental Information Disclosure Statement is being filed within three months of the filing date of the application or before the mailing of a first Office Action, whichever occurs last. Therefore, no fee is believed to be required. However, in the event that a fee is required for filing this Supplemental Information Disclosure Statement, please charge the fee specified under 37 C.F.R. § 1.17(p) to Deposit Account No. 23-0925.

Respectfully submitted,

Dated: 10-8-62

Mark S. Matkin Reg. No. 32,268 OC 1 5 2002

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SERIAL NO. 09/943.190

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APPLICANT: Kristy A. Compbell et al.

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	АВ	3,743,847	07/03/73	Boland	250	510		
	AC	4,269,935	05/26/81	Masters et al.	430	323		
	AD	4,312,938	01/26/82	Drexler et al.	430	496		
	ΑE	4,320,191	03/16/82	Yoshikawa et al.	430	296		
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	AN	Owens et a	I., Metal-Cha	alcogenid	le Photoresists for High Re	esolution Lith	ography a	nd Sub-N	<i>licron</i>	
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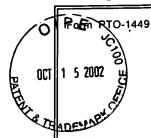
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